

Supplementary Materials

Magnetic field-governed kinetics in silicon dioxide-based anode towards high performing lithium-ion magneto-batteries

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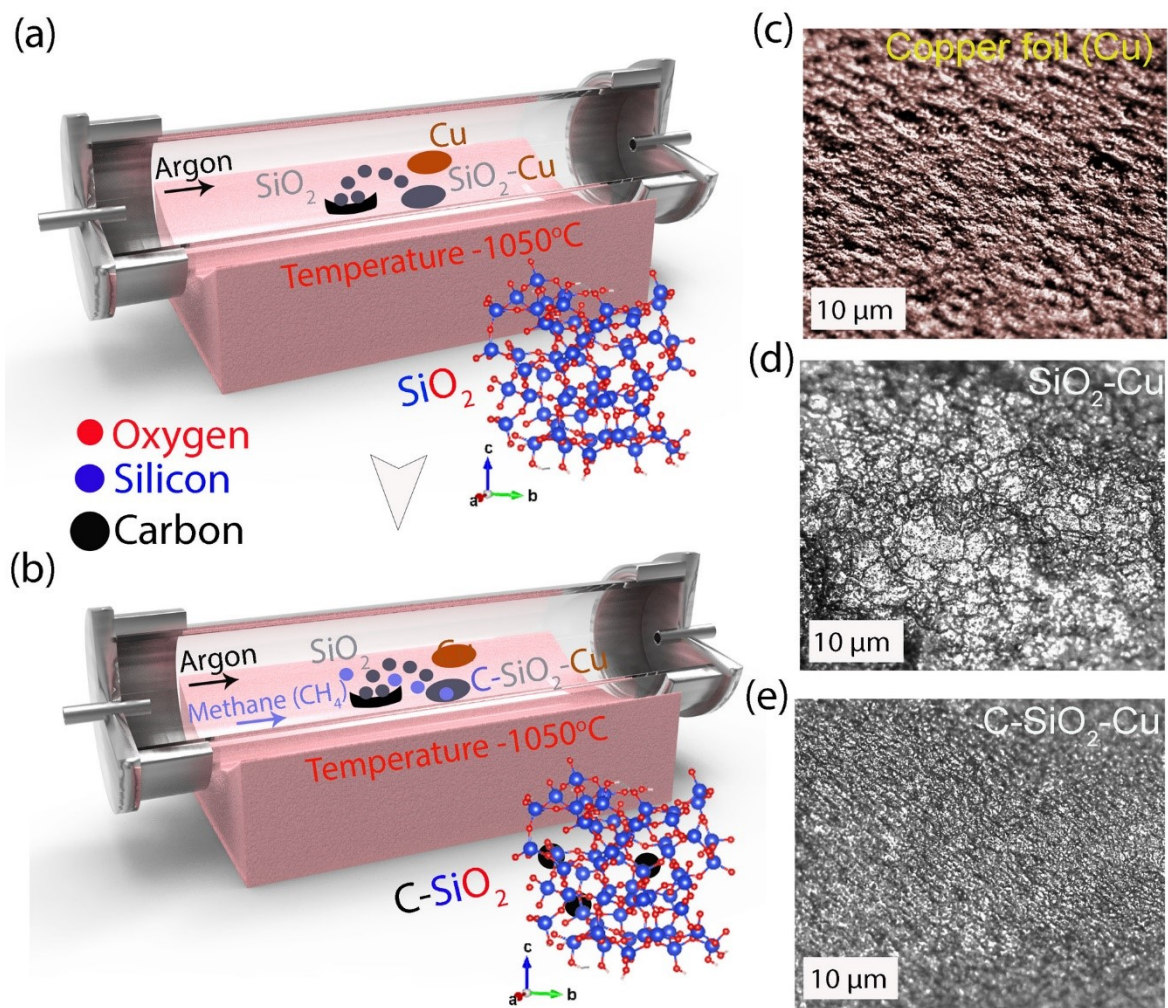


Fig. S1. Schematic presentation of the deposition of SiO₂ and carbon on the surface of Cu foil using CVD technique: (a) direct deposition of SiO₂ on the surface of copper (SiO₂/Cu sample) and (b) direct deposition of SiO₂ and carbon (CH₄ is used as a source of carbon) on the surface of copper (C-SiO₂/Cu sample). (c-e) surface analysis by optical microscope: (c) Cu-foil surface, (d) surface of SiO₂ particles deposited on Cu foil (SiO₂ shows shiny surface), and (e) carbon incorporated SiO₂ particles deposited on Cu foil (reduces the shiny surface and trends to darker due to carbon deposition).



Fig. S2. (a-c) Optical microscopy images: (a) Cu-foil surface (inset digital image), (b) surface of SiO₂ particles deposited on Cu foil (inset digital image), and (c) carbon incorporated SiO₂ particles deposited on Cu foil (inset digital image). A significant surface color changes after deposition of SiO₂ and carbon.

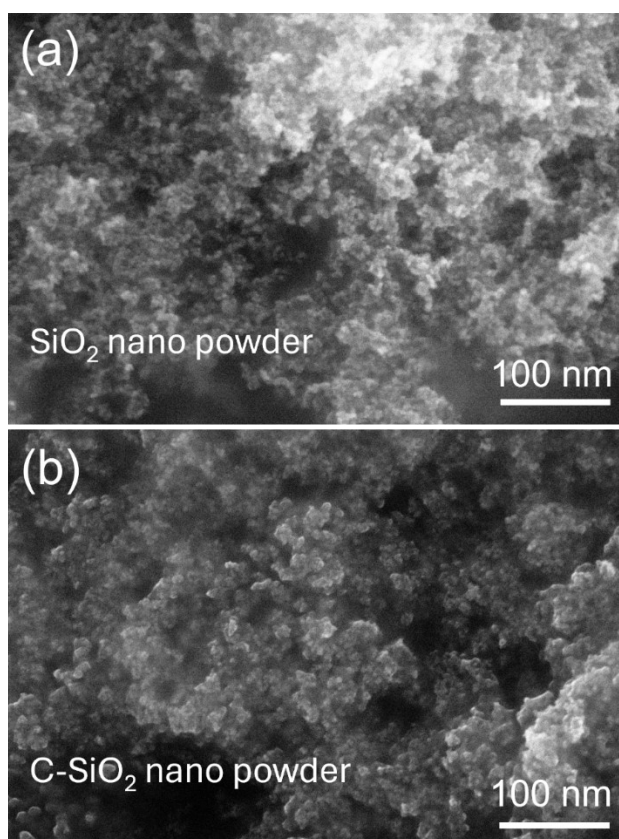


Fig. S3. SEM images of the SiO₂ and C-SiO₂ nano powders before deposition on the copper surface.

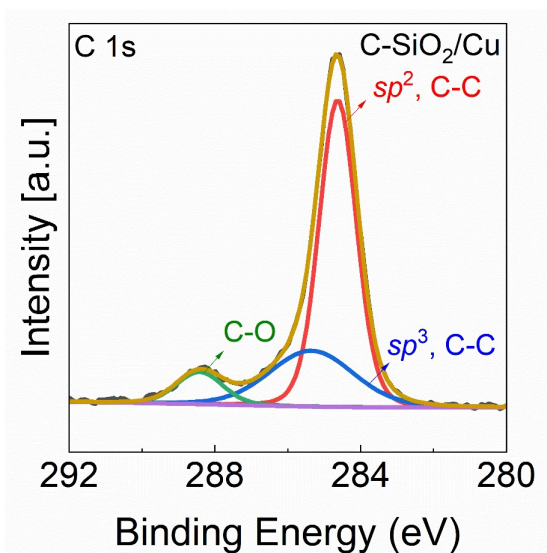


Fig. S4. C 1s spectra of the C-SiO₂/Cu sample.

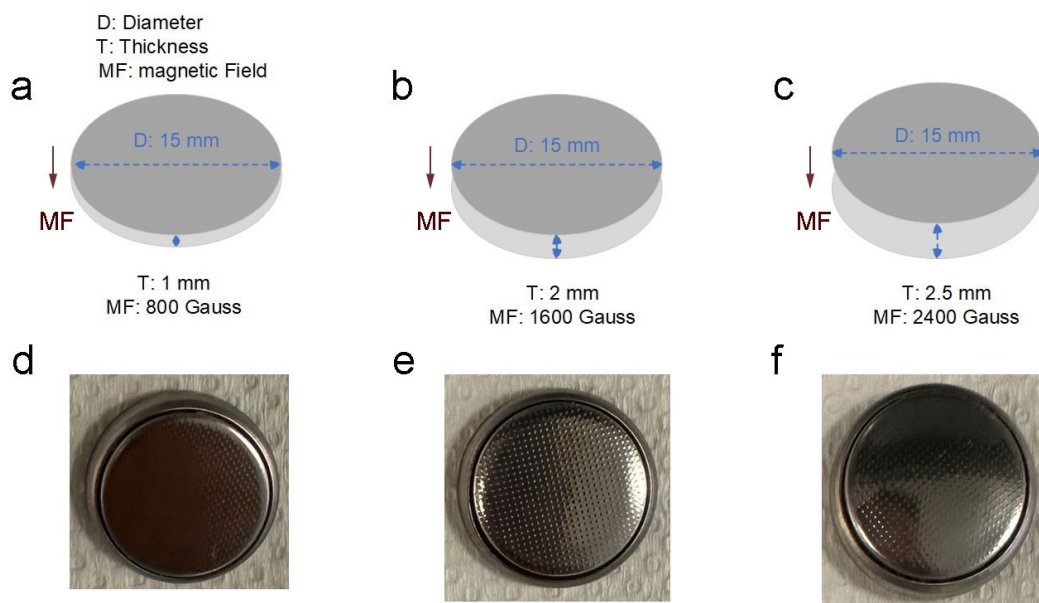


Fig. S5. Different magnetic spacers: (a) 15 × 1 mm- 800 Gauss, (b) 15 × 2 mm- 1600 Gauss and (c) 15 × 2.5 mm- 2400 Gauss used to assemble CR-2032-coin cells (d, e, f), respectively.

Table S1. Comparison of the battery performance of the SiO_x based materials with present results.

Materials	Initial discharge -charge capacity	Initial Coulombic efficiency	Cycling performance	Rate performance	Ref.
SiO _x -graphene/C	896/607 mAh g ⁻¹	67.7 %	630 mAh g ⁻¹ at 100 mA g ⁻¹ after 250 cycles	408 mAh g ⁻¹ at 600 mA g ⁻¹	[44]
SiO _x /C	1475/1015 mAh g ⁻¹	68.8 %	817 mAh g ⁻¹ at 100 mA g ⁻¹ after 100 cycles	650 mAh g ⁻¹ at 800 mA g ⁻¹	[45]
SiO _x /C	1324/906 mAh g ⁻¹	68.4 %	720 mAh g ⁻¹ at 100 mA g ⁻¹ after 350 cycles	410 mAh g ⁻¹ at 800 mA g ⁻¹	[46]
SiO _x /MWCNT/C	1093/720 mAh g ⁻¹	66 %	620 mAh g ⁻¹ at 100 mA g ⁻¹ after 450 cycles	388 mAh g ⁻¹ at 800 mA g ⁻¹	[47]
SiO ₂ /C	880/530 mAh g ⁻¹	68 %	441 mAh g ⁻¹ at 500 mA g ⁻¹ after 500 cycles	231 mAh g ⁻¹ at 2A g ⁻¹	[48]
SiO _x /Graphite	785/645 mAh g ⁻¹	82.2 %	580 mAh g ⁻¹ at 325 mA g ⁻¹ after 500 cycles	549 mAh g ⁻¹ at 3A g ⁻¹	[49]
Carbon coating lemon-like SiO ₂ hollow spheres	451/203 mAh g ⁻¹	< 50 %	786 mAh g ⁻¹ at 1 Ag ⁻¹ after 500 cycles	681 mAh g ⁻¹ at 2A g ⁻¹	[50]
Nanotubular SiO ₂ @C composite	-	50.5 %	526 mAh g ⁻¹ at 1 A g ⁻¹ after 500 cycles	~ 600 mAh g ⁻¹ at 2A g ⁻¹	[51]
Rice Husk-Derived SiO ₂ /C Composites	-	60 %	730 mAh g ⁻¹ at 100 mA g ⁻¹ after 100 cycles	480 mAh g ⁻¹ at 1A g ⁻¹	[52]
3D PAA-TA/SiO _x	2328/1550	66.7%.	1025 mAh g ⁻¹ at 500 mA g ⁻¹ after 250cycles	670 mAh g ⁻¹ at 2A g ⁻¹	[53]
Porous carbon rich SiO _x /C	718/650	90%	533 at 200 mA g ⁻¹ 200 cycles	299 mAh g ⁻¹ at 1A g ⁻¹	[54]
SiO _x /G/C anode	790/660	83%	487 mAh g ⁻¹ at 300 mA g ⁻¹ after 500 cycles	650 mAh g ⁻¹ at 1.2 A g ⁻¹	[55]
Carbon coated C-SiO ₂ (under magnetic field)	1757/1686	96%	2020 mAh g ⁻¹ at 100 mA g ⁻¹ after 750 cycles	891 mAh g ⁻¹ at 2A g ⁻¹ .	This Work

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